

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (Ultra-High-Speed U-MOSIII)

TPCA8003-H

High Efficiency DC/DC Converter Applications
 Notebook PC Applications
 Portable Equipment Applications

Unit: mm

- Small footprint due to a small and thin package
- High speed switching
- Small gate charge: $Q_{SW} = 8.4 \text{ nC (typ.)}$
- Low drain-source ON-resistance: $R_{DS(ON)} = 5.1 \text{ m}\Omega \text{ (typ.)}$
- High forward transfer admittance: $|Y_{fs}| = 60\text{S (typ.)}$
- Low leakage current: $I_{DSS} = 10 \mu\text{A (max)}$ ($V_{DS} = 30 \text{ V}$)
- Enhancement mode: $V_{th} = 1.1 \text{ to } 2.3 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

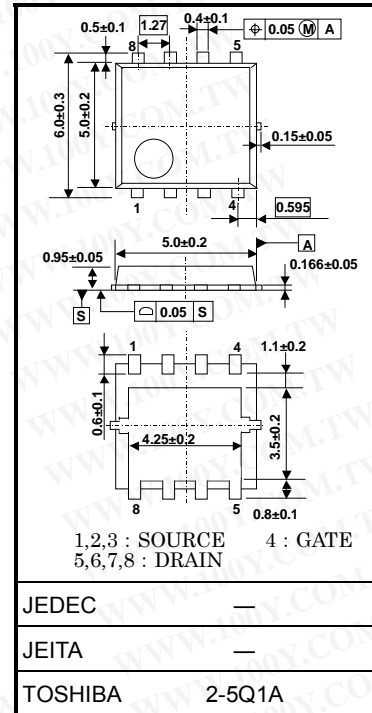
Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	30	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	30	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	35	A
	Pulsed (Note 1)	I_{DP}	105	
Drain power dissipation ($T_c=25^\circ\text{C}$)		P_D	45	W
Drain power dissipation ($t = 10 \text{ s}$) (Note 2a)		P_D	2.8	W
Drain power dissipation ($t = 10 \text{ s}$) (Note 2b)		P_D	1.6	W
Single-pulse avalanche energy (Note 3)		E_{AS}	159	mJ
Avalanche current		I_{AR}	35	A
Repetitive avalanche energy ($T_c=25^\circ\text{C}$) (Note 4)		E_{AR}	4.5	mJ
Channel temperature		T_{ch}	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 to 150	$^\circ\text{C}$

Note: For Notes 1 to 4, refer to the next page.

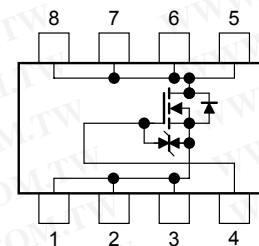
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.069 g (typ.)

Circuit Configuration

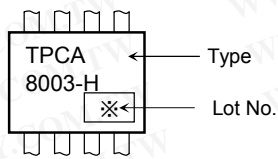


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Thermal Characteristics

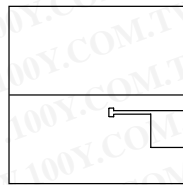
Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case ($T_c=25^\circ\text{C}$)	$R_{th(ch-c)}$	2.78	$^\circ\text{C/W}$
Thermal resistance, channel to ambient ($t = 10\text{ s}$) (Note 2a)	$R_{th(ch-a)}$	44.6	$^\circ\text{C/W}$
Thermal resistance, channel to ambient ($t = 10\text{ s}$) (Note 2b)	$R_{th(ch-a)}$	78.1	$^\circ\text{C/W}$

Marking (Note 5)



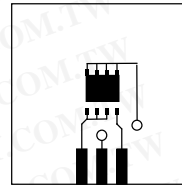
Note 1: The channel temperature should not exceed 150°C during use.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



(a)

FR-4
 $25.4 \times 25.4 \times 0.8$
 (Unit: mm)



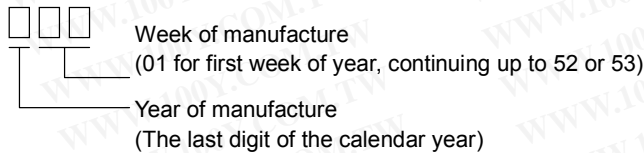
(b)

FR-4
 $25.4 \times 25.4 \times 0.8$
 (Unit: mm)

Note 3: $V_{DD} = 24\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 0.1\text{ mH}$, $R_G = 25\ \Omega$, $I_{AR} = 35\text{ A}$

Note 4: Repetitive rating: pulse width limited by max. channel temperature

Note 5: * Weekly code: (Three digits)



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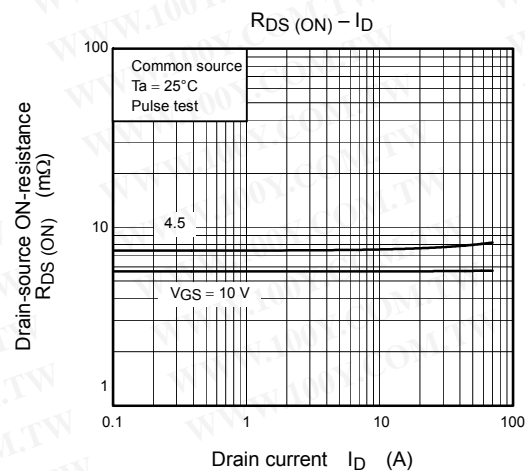
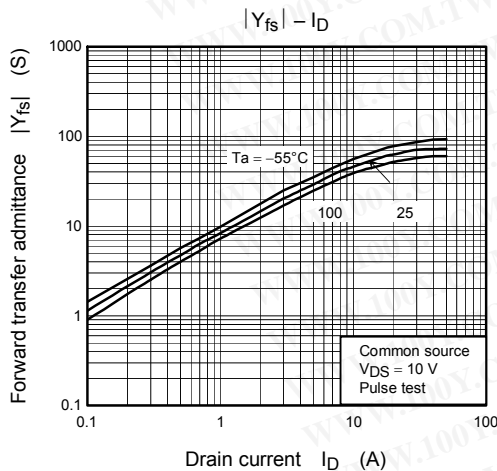
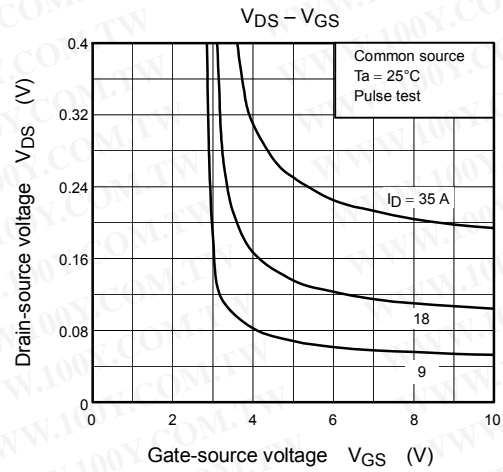
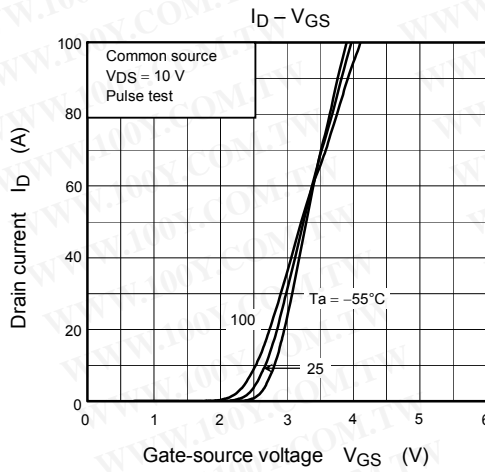
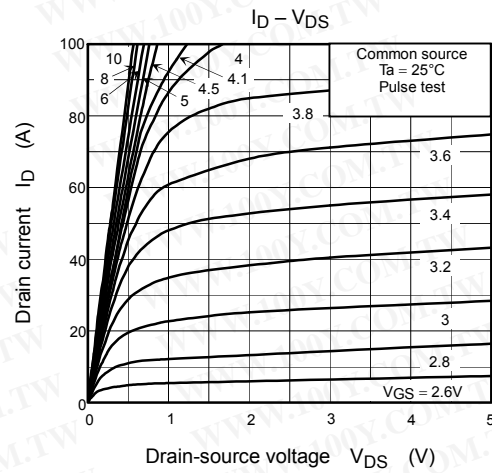
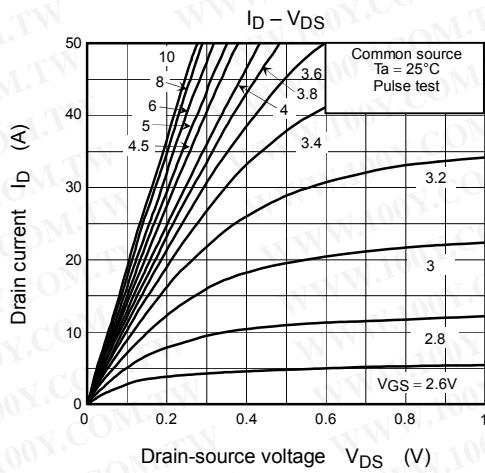
Electrical Characteristics (Ta = 25°C)

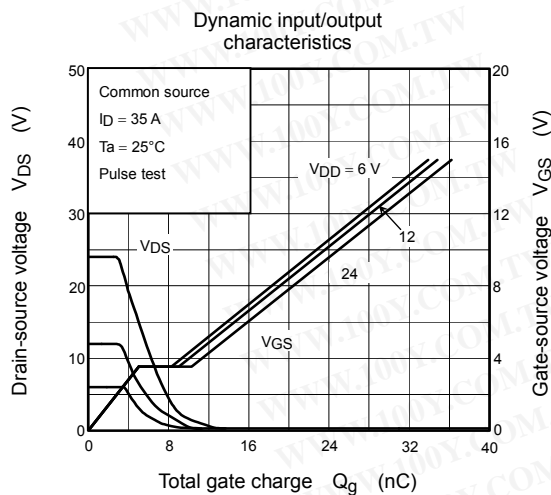
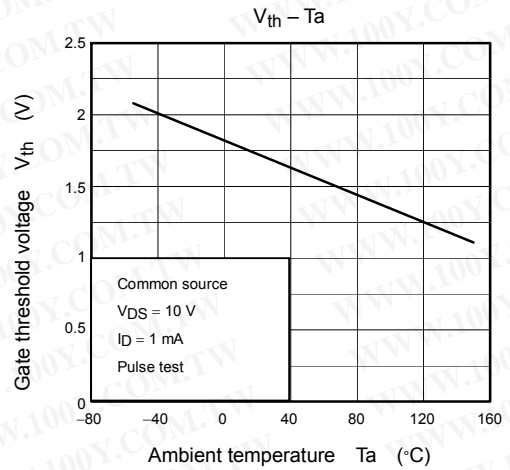
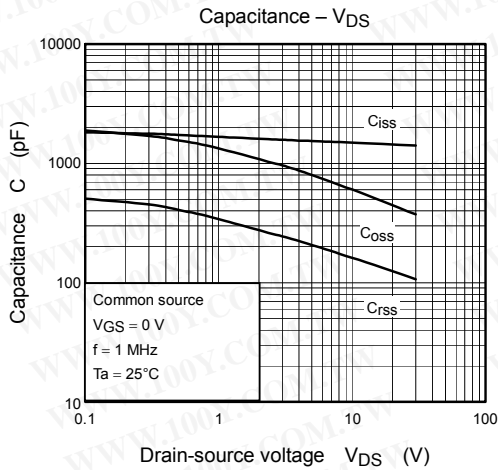
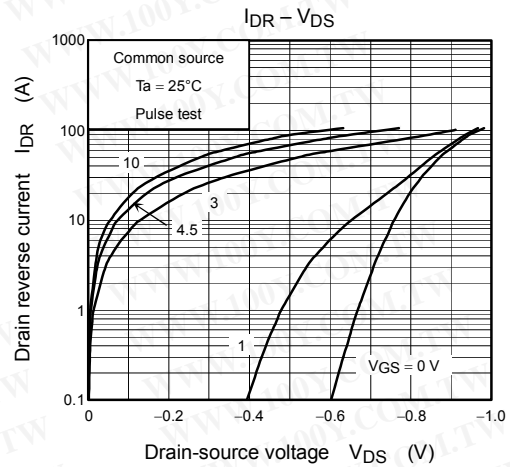
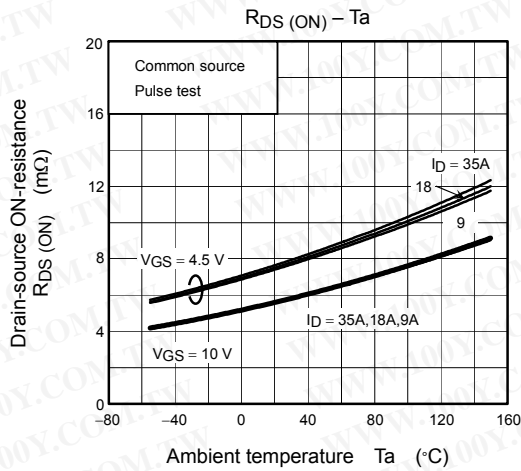
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$	—	—	± 10	μA
Drain cutoff current		I_{DSS}	$V_{DS} = 30\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	μA
Drain-source breakdown voltage		$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	30	—	—	V
		$V_{(BR)DSX}$	$I_D = 10\text{ mA}, V_{GS} = -20\text{ V}$	15	—	—	
Gate threshold voltage		V_{th}	$V_{DS} = 10\text{ V}, I_D = 1\text{ mA}$	1.1	—	2.3	V
Drain-source ON-resistance		$R_{DS(ON)}$	$V_{GS} = 4.5\text{ V}, I_D = 18\text{ A}$	—	7.3	9.5	m Ω
			$V_{GS} = 10\text{ V}, I_D = 18\text{ A}$	—	5.1	6.6	
Forward transfer admittance		$ Y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 18\text{ A}$	30	60	—	S
Input capacitance		C_{iss}	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	1465	—	pF
Reverse transfer capacitance		C_{rss}		—	175	—	
Output capacitance		C_{oss}		—	610	—	
Switching time	Rise time	t_r	<p> $V_{GS} = 10\text{ V}$ 0 V $I_D = 18\text{ A}$ V_{OUT} $4.7\ \Omega$ $R_L = 0.83\ \Omega$ $V_{DD} \approx 15\text{ V}$ $Duty \leq 1\%, t_w = 10\ \mu\text{s}$ </p>	—	4	—	ns
	Turn-on time	t_{on}		—	11	—	
	Fall time	t_f		—	10	—	
	Turn-off time	t_{off}		—	36	—	
Total gate charge (gate-source plus gate-drain)		Q_g	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 35\text{ A}$	—	25	—	nC
			$V_{DD} \approx 24\text{ V}, V_{GS} = 5\text{ V}, I_D = 35\text{ A}$	—	13	—	
Gate-source charge 1		Q_{gs1}	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 35\text{ A}$	—	5.8	—	
Gate-drain ("Miller") charge		Q_{gd}	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 35\text{ A}$	—	5.1	—	
Gate switch charge		Q_{sw}	$V_{DD} \approx 24\text{ V}, V_{GS} = 10\text{ V}, I_D = 35\text{ A}$	—	8.4	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

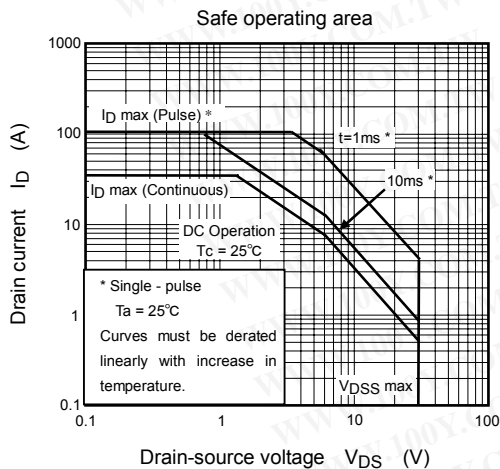
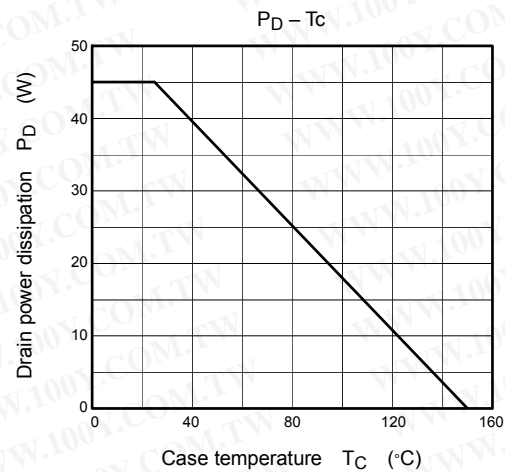
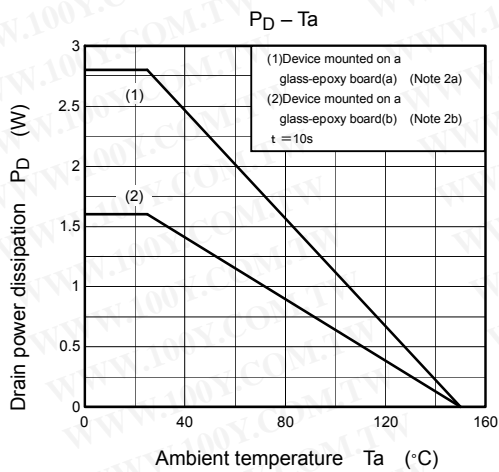
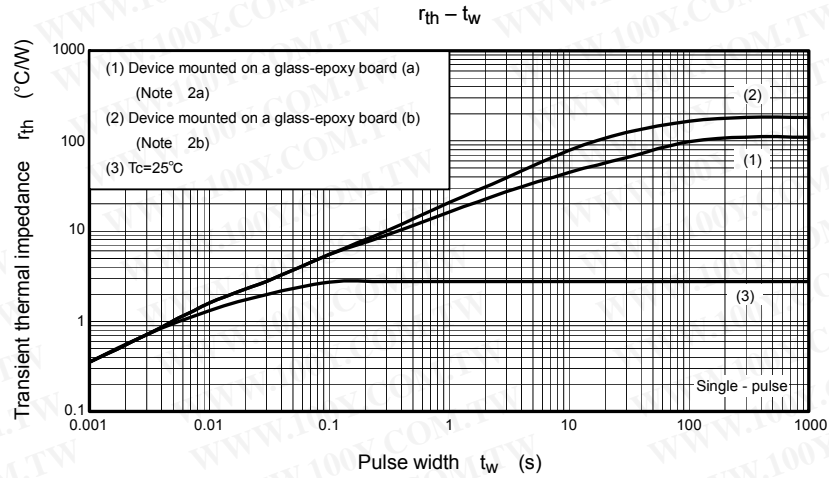
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current	Pulse (Note 1)	I_{DRP}	—	—	—	105	A
Forward voltage (diode)		V_{DSF}	$I_{DR} = 35\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.2	V

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